

BSZ034N04LSATMA1

BSZ034N04LSATMA1 Information

	Transistors - FETs, MOSFETs - Single Dtion MOSFET N-CH 40V 19A 8TSDSON e 8-PowerTDFN For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BSZ034N04LSATMA1 Specifications

Manufacturer Part Number	BSZ034N04LSATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	Automotive, AEC-Q101, OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	19A (Ta), 40A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1800pF @ 20V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	2.1W (Ta), 52W (Tc)
Rds On (Max) @ Id, Vgs	3.4 mOhm @ 20A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-TSDSON-8-FL
Package / Case	8-PowerTDFN
	Report errors?

BSZ034N04LSATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

BSZ034N04LSATMA1 Payment Methods



BSZ034N04LSATMA1 Shipping Methods



If you have any question about BSZ034N04LSATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com